

1200V/40A Silicon Carbide Power Schottky Barrier Diode

Features

- Rated to 1200V at 40 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- High temperature operation
- High frequency operation

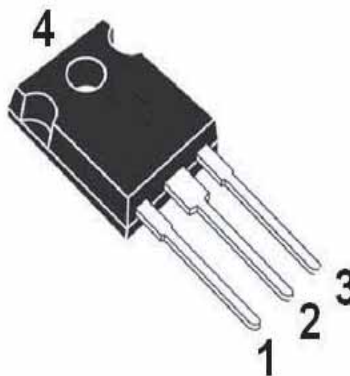
Key Characteristics		
V_{RRM}	1200	V
$I_F, T_c \leq 135^\circ\text{C}$	40	A
Q_c	232	nC

Benefits

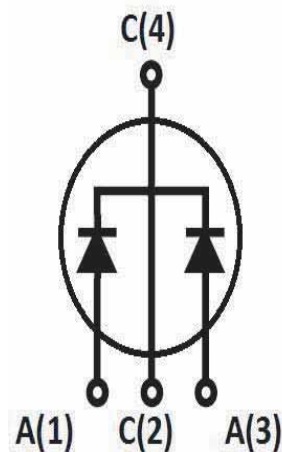
- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV



Package:
TO-247



Part No.	Package Type	Marking
SC3S12040B	TO-247-3 pin	12040

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		1200	V
Surge Peak Reverse Voltage	V_{RSM}		1200	
DC Blocking Voltage	V_{DC}		1200	
Continuous Forward Current	I_F	$T_C=25^{\circ}C$ $T_C=135^{\circ}C$	44* 20*	A
Repetitive Peak Forward Surge Current	I_{FRM}	$T_C=25^{\circ}C$, $t_p=10ms$, Half Sine Wave, $D=0.3$	100*	A
Non-repetitive Peak Forward Surge Current	I_{FSM}	$T_C=25^{\circ}C$, $t_p=10ms$, Half Sine Wave	140*	A
Power Dissipation	P_{TOT}	$T_C=25^{\circ}C$	192.3*	W
		$T_C=110^{\circ}C$	85	W
Operating Junction	T_j		-55 $^{\circ}C$ to 175 $^{\circ}C$	$^{\circ}C$
Storage Temperature	T_{stg}		-55 $^{\circ}C$ to 175 $^{\circ}C$	$^{\circ}C$
Mounting Torque		M3 Screw 6-32 Screw	1	Nm lbf-in
			8.8	

* Per leg ; ** Per diode

Thermal Characteristics

Parameter	Symbol	Test Condition	Value	Unit
			Typ.	
Thermal resistance from junction to case	R_{thJC}		0.78* 0.39**	$^{\circ}C/W$

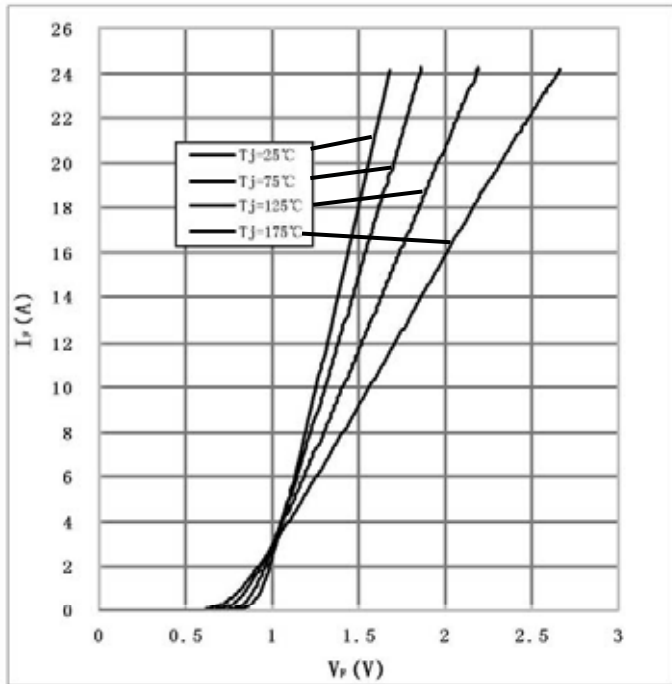
* Per leg ; ** Per diode

Electrical Characteristics

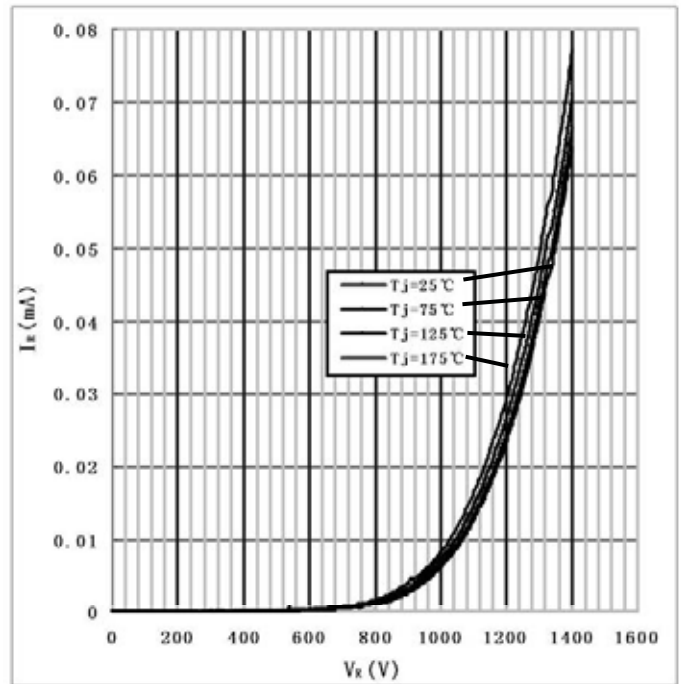
Parameter	Symbol	Test Conditions	Numerical		Unit
			Typ.	Max.	
Forward Voltage	V_F	$I_F=20A$, $T_j=25^{\circ}C$	1.6	1.8	V
		$I_F=20A$, $T_j=175^{\circ}C$	2.4	3	
Reverse Current	I_R	$V_R=1200V$, $T_j=25^{\circ}C$	50	100	μA
		$V_R=1200V$, $T_j=175^{\circ}C$	100	200	
Total Capacitive Charge	Q_C	$V_R=800V$, $T_j=150^{\circ}C$ $Q_C = \int_0^{V_R} C(V)dV$	116	-	nC
Total Capacitance	C	$V_R=0V$, $T_j=25^{\circ}C$, $f=1MHz$	1640	1800	pF
		$V_R=400V$, $T_j=25^{\circ}C$, $f=1MHz$	105	108	
		$V_R=800V$, $T_j=25^{\circ}C$, $f=1MHz$	103	104	

RATING AND CHARACTERISTICS CURVES(SC3S12040B)

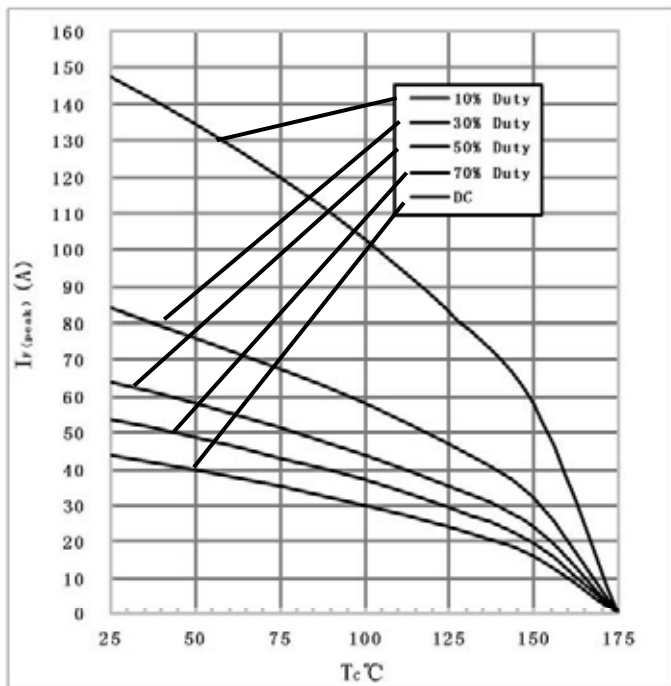
1) Forward IV characteristics as a function of T_j :



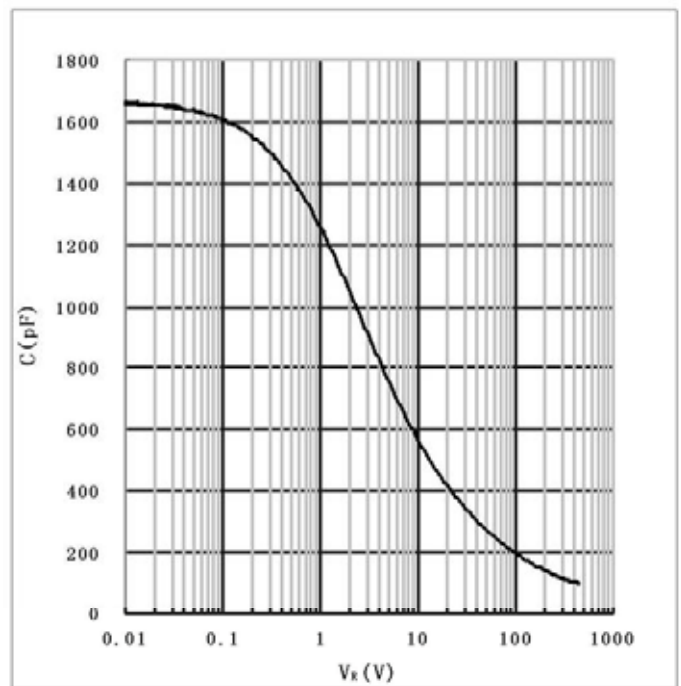
2) Reverse IV characteristics as a function of T_j :



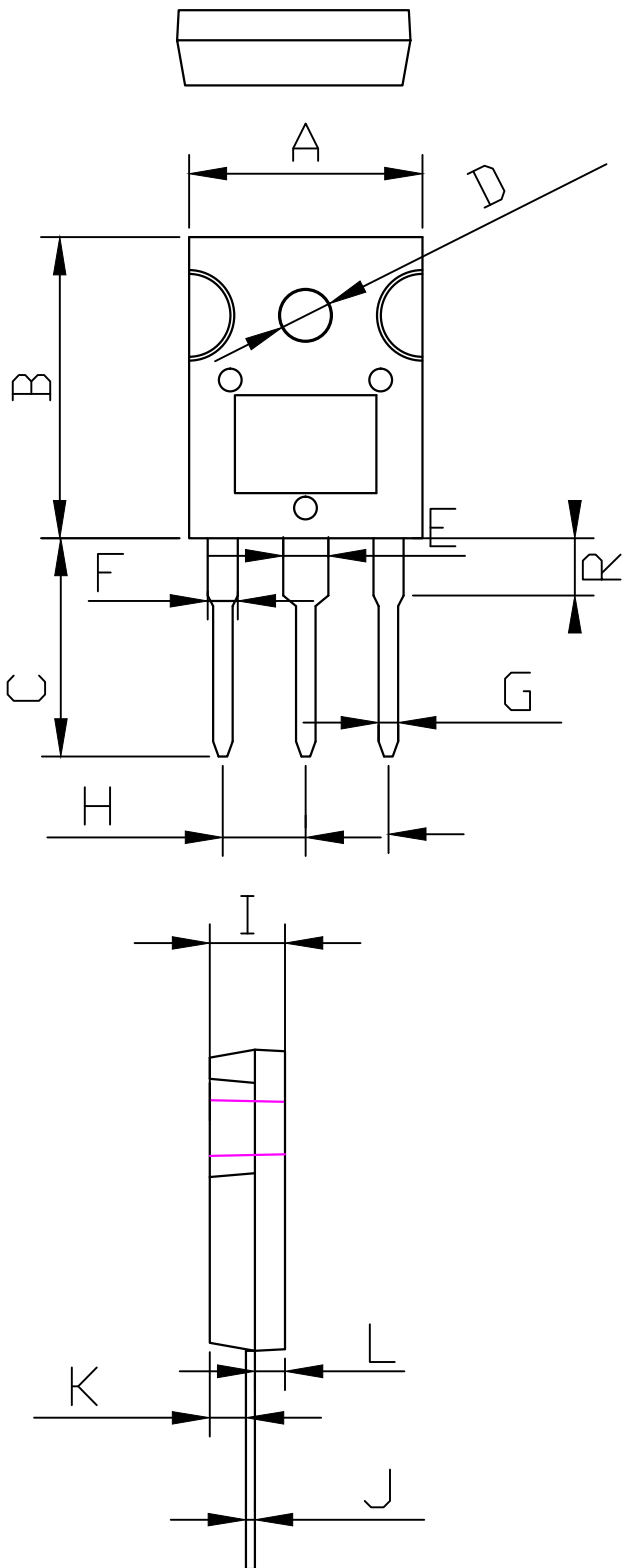
3) Current Derating



4) Capacitance vs. reverse voltage :



TO-247



项目	mm		
	标准值	Min	Max
A	15.5	15.45	15.55
B	20	19.9	20.1
C	14.5	14.4	14.6
D	3.5	3.3	3.6
E	3	2.95	3.05
F	2	1.95	2.05
G	1.3	1.2	1.4
H	5.5	5.4	5.6
I	5	4.95	5.05
J	0.6	0.58	0.62
K	2.4	2.3	2.5
L	2	1.9	2.1
R	3.8	3.6	4

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